

**EAST - [10729090.wsp:1]**

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L1: (1923) optical and mesa and cladding  
 L2: (449) optical near device and mesa and cladding  
 L3: (1112) 1 and (indium near phosphide InP)  
 L4: (1) 1 and (indium near phosphide InP) and (phosphorous near trichloride PCl<sub>3</sub>)  
 L5: (1) 1 and (indium near phosphide) and (phosphorous near trichloride PCl<sub>3</sub>)  
 L6: (1) 1 and (indium near phosphide) and (phosphorous near trichloride)  
 L7: (221) 1 and (indium near phosphide)  
 L8: (1112) 1 and (indium near phosphide InP)  
 L9: (1608) optical and mesa and cladding near layer  
 L10: (408) optical near device and mesa and cladding near layer

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optical near device and mesa and cladding near layer

	U	I	Document ID	Issue Date	Pages	Title	Current OR	Current XRef
100	<input type="checkbox"/>	<input type="checkbox"/>	US 20030006407 A1	20030109	17	Apparatus and a method of fabricating inversion channel devices with precision gate doping for a monolithic integrated circuit	257/12	257/184; 257/E29.25
101	<input type="checkbox"/>	<input type="checkbox"/>	US 20030062556 A1	20030102	12	Semiconductor laser device, a semiconductor laser array, and a method for aligning optical fibers with the device or array	372/50	372/46
102	<input type="checkbox"/>	<input type="checkbox"/>	US 20020167580 A1	20021212	34	Semiconductor optical device and the fabrication method	438/47	
103	<input type="checkbox"/>	<input type="checkbox"/>	US 20020187579 A1	20021212	10	METHOD FOR MANUFACTURING A SEMICONDUCTOR OPTICAL FUNCTIONAL DEVICE	438/43	438/38; 438/40
104	<input type="checkbox"/>	<input type="checkbox"/>	US 20020186736 A1	20021212	33	METHOD FOR FABRICATING SEMICONDUCTOR DEVICE AND SEMICONDUCTOR DEVICE	372/50	257/E21.108; 257/E21.119
105	<input type="checkbox"/>	<input type="checkbox"/>	US 20020179930 A1	20021205	40	Composite semiconductor structure and device with optical testing elements	257/190	
106	<input type="checkbox"/>	<input type="checkbox"/>	US 20020179929 A1	20021205	57	Semiconductor optical modulator, an optical amplifier and an integrated semiconductor light-emitting device	257/184	
107	<input type="checkbox"/>	<input type="checkbox"/>	US 20020175325 A1	20021128	14	Semiconductor optical devices	257/25	
108	<input type="checkbox"/>	<input type="checkbox"/>	US 20020168856 A1	20021114	11	Semi-insulating substrate, semiconductor optical device and fabrication method of semiconductor thin film	438/689	257/E33.027; 428/637; 478/647
109	<input type="checkbox"/>	<input type="checkbox"/>	US 20020163948 A1	20021107	41	Semiconductor laser device having a diffraction grating on a light emission side	372/45	372/96
110	<input type="checkbox"/>	<input type="checkbox"/>	US 20020163688 A1	20021107	26	Optical communications system and vertical cavity surface emitting laser therefor	398/144	398/82; 398/91